Low-ohmic single-pole double-throw analog switch

Rev. 10 — 7 August 2012

**Product data sheet** 

### 1. General description

The NX3L1G3157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z). Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times.

The NX3L1G3157 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from Z to Y0 or Y1; or from Y0 or Y1 to Z. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

# 2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance:
  - 1.6  $\Omega$  (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0  $\Omega$  (typical) at V<sub>CC</sub> = 1.65 V
  - 0.55  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - ◆ IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Low-ohmic single-pole double-throw analog switch

# 3. Applications

- Cell phone
- PDA
- Portable media player

# 4. Ordering information

#### Table 1.Ordering information

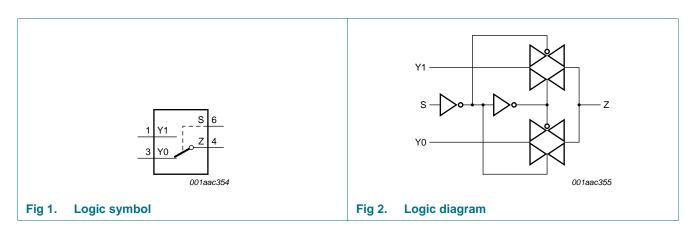
Type number	Package										
	Temperature range	Name	Description	Version							
NX3L1G3157GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363							
NX3L1G3157GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886							

# 5. Marking

Table 2.	Marking codes <sup>[1]</sup>	
Type num	iber	Marking code
NX3L1G3	157GW	MJ
NX3L1G3	157GM	MJ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

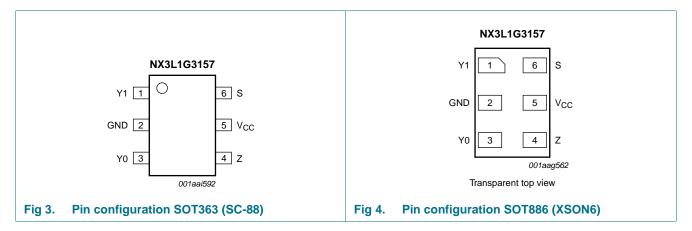
# 6. Functional diagram



Low-ohmic single-pole double-throw analog switch

# 7. Pinning information

### 7.1 Pinning



### 7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V <sub>CC</sub>	5	supply voltage
S	6	select input

# 8. Functional description

#### Table 4.Function table

Input S	Channel on
L	YO
Н	Y1

[1] H = HIGH voltage level; L = LOW voltage level.

Low-ohmic single-pole double-throw analog switch

### 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V <sub>SW</sub>	switch voltage		2 -0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 V$	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current	-	±350	mA
		V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SC-88 package: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

# 10. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V <sub>SW</sub>	switch voltage		[1] 0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current flows from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

Low-ohmic single-pole double-throw analog switch

# **11. Static characteristics**

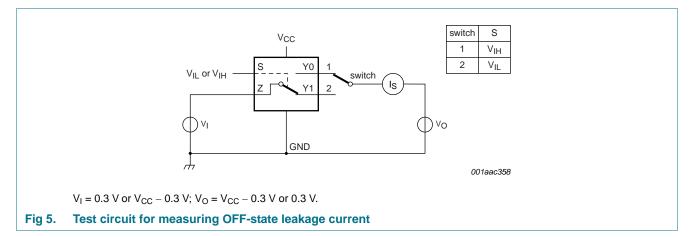
#### Table 7. Static characteristics

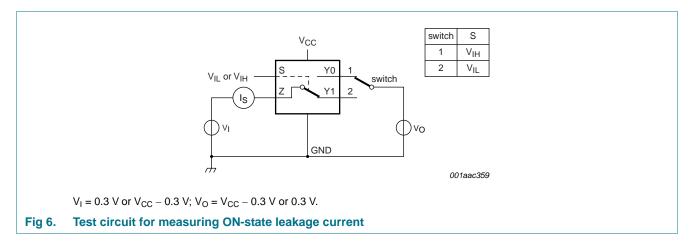
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Tar	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C		
			Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	
V <sub>IH</sub>	HIGH-level	$V_{CC} = 1.4 \text{ V}$ to 1.95 V	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	-	V
	input voltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7	-	-	1.7	-	-	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	2.0	-	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
V <sub>IL</sub>	LOW-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	$0.35V_{CC}$	V
	input voltage	$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	-	0.7	0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	0.8	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
I	input leakage current	select input S; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
$I_{S(OFF)}$	OFF-state leakage	Y0 and Y1 port; see <u>Figure 5</u>							
	current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state	Z port; see Figure 6							
	leakage current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	130	-	-	-	-	pF

Low-ohmic single-pole double-throw analog switch

### 11.1 Test circuits





#### Low-ohmic single-pole double-throw analog switch

### 11.2 ON resistance

#### Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

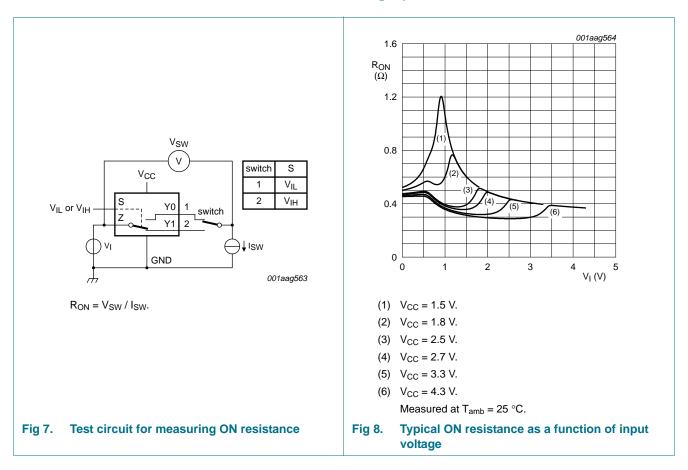
Symbol	Parameter	Conditions	T <sub>amb</sub> = -	–40 °C to	+85 °C	$T_{amb}$ = -40 °	C to +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND$ to $V_{CC}$ ; $I_{SW} = 100 \text{ mA}$ ; see Figure 7						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_I = GND \text{ to } V_{CC};$ [2] $I_{SW} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V <sub>CC</sub> = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ [3] $I_{SW} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V <sub>CC</sub> = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC}$ = 2.3 V	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC}$ = 4.3 V	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ .

[2] Measured at identical V<sub>CC</sub>, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

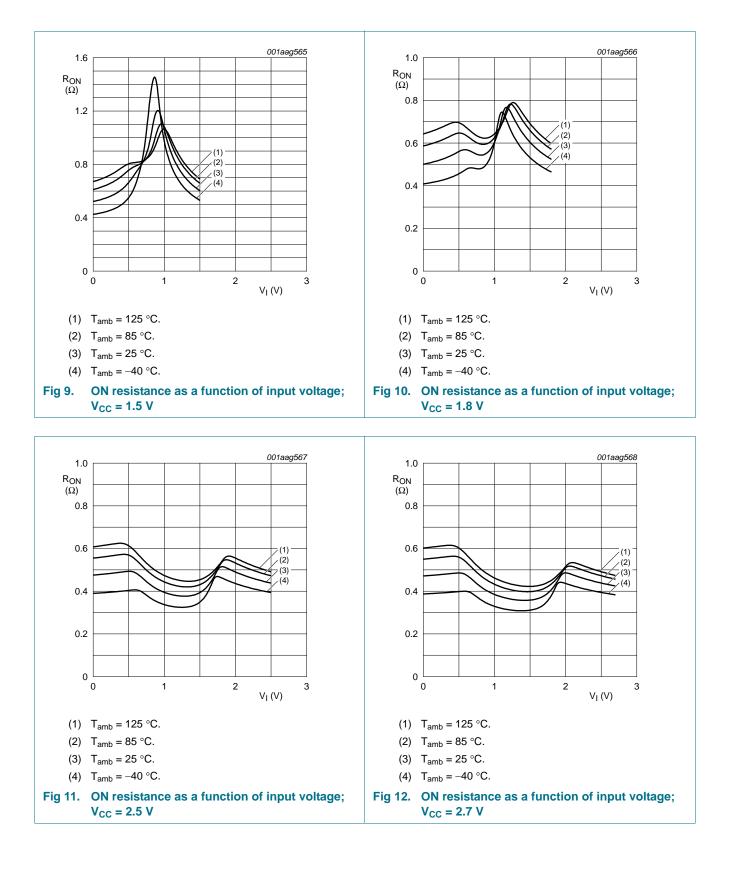
Low-ohmic single-pole double-throw analog switch



### 11.3 ON resistance test circuit and graphs

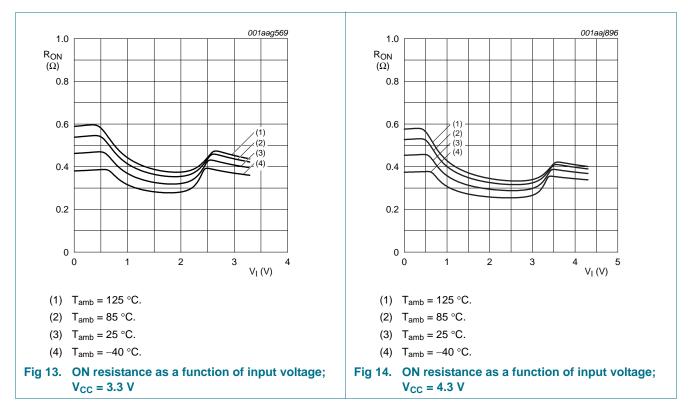
NX3L1G3157 Product data sheet

# NX3L1G3157



# NX3L1G3157

Low-ohmic single-pole double-throw analog switch



### **12. Dynamic characteristics**

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	S to Z or Yn; see <u>Figure 15</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	28	43	-	48	52	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	23	35	-	38	42	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	17	27	-	29	32	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	14	25	-	27	30	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	14	25	-	27	30	ns
t <sub>dis</sub>	disable time	S to Z or Yn; see <u>Figure 15</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	9	20	-	25	30	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	6	15	-	20	23	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	5	11	-	14	16	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	4	10	-	12	14	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	4	10	-	12	14	ns

10 of 22

#### Low-ohmic single-pole double-throw analog switch

Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			Unit
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>b-m</sub> break-before-make time	see Figure 16	[2]					•			
	time	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		-	19	-	4	-	-	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		-	17	-	4	-	-	ns
		$V_{CC}$ = 2.3 V to 2.7 V		-	13	-	2	-	-	ns
		$V_{CC}$ = 2.7 V to 3.6 V		-	10	-	2	-	-	ns
		$V_{CC}$ = 3.6 V to 4.3 V		-	10	-	2	-	-	ns

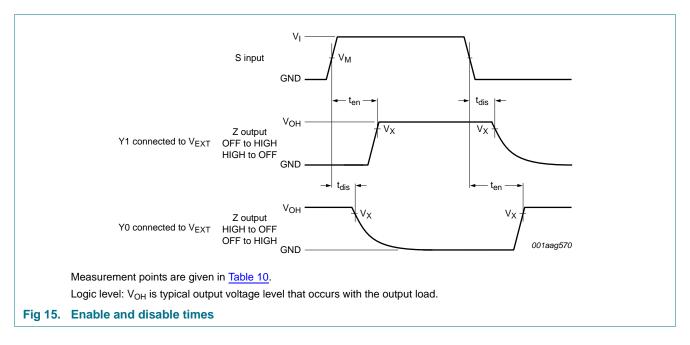
#### Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

### 12.1 Waveform and test circuits

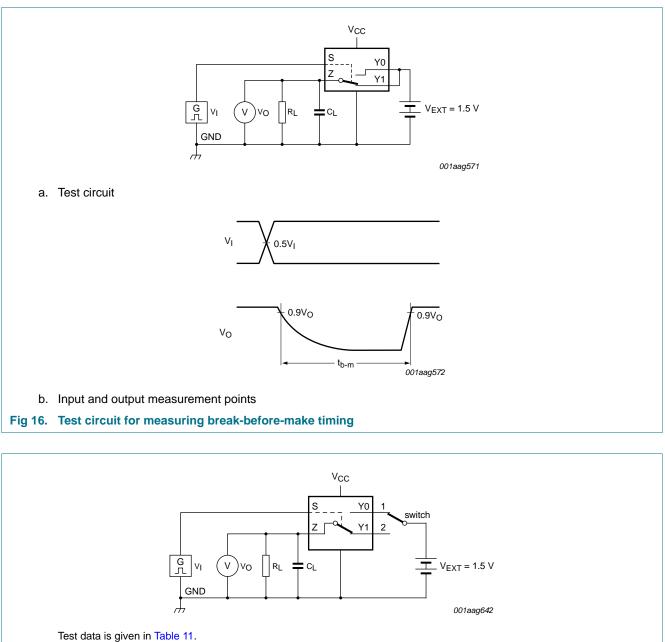


#### Table 10. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

# NX3L1G3157

#### Low-ohmic single-pole double-throw analog switch



Definitions test circuit:

 $R_L$  = Load resistance.

- $C_L$  = Load capacitance including jig and probe capacitance.
- V<sub>EXT</sub> = External voltage for measuring switching times.

#### Fig 17. Load circuit for switching times

#### Table 11. Test data

Supply voltage	Input		Load	
V <sub>cc</sub>	V <sub>I</sub> t <sub>r</sub> , t <sub>f</sub>		CL	RL
1.4 V to 4.3 V	V <sub>CC</sub>	$\leq$ 2.5 ns	35 pF	50 Ω

NX3L1G3157	
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Low-ohmic single-pole double-throw analog switch

### 12.2 Additional dynamic characteristics

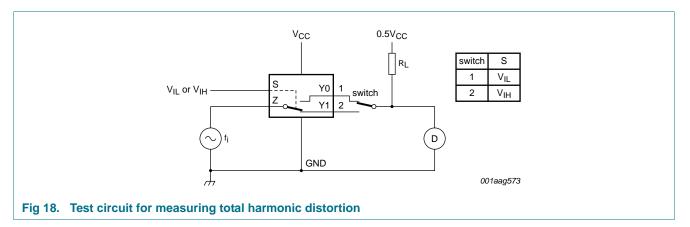
#### Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
THD	total harmonic distortion	$f_i = 20 \text{ Hz to } 20 \text{ kHz}; \text{ R}_L = 32 \Omega; \text{ see } \frac{\text{Figure } 18}{1000 \text{ sec } 18}$	[1]			
		V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)	-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)	-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
f <sub>(-3dB)</sub>	–3 dB frequency response	$R_L = 50 \Omega$ ; see <u>Figure 19</u>	<u>[1]</u>			
. ,		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	60	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{100 \text{ kHz}}$	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	-90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 21				
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	0.3	-	V
Q <sub>inj</sub>	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 22}}{2}$				
		$V_{CC} = 1.5 V$	-	3	-	рС
		V <sub>CC</sub> = 1.8 V	-	4	-	рС
		$V_{CC} = 2.5 V$	-	6	-	рС
		$V_{CC} = 3.3 V$	-	9	-	pC
		$V_{CC} = 4.3 V$	-	15	-	рС

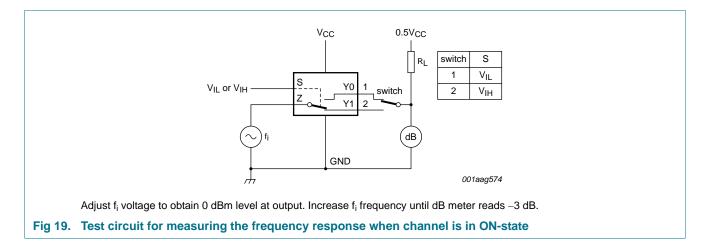
[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

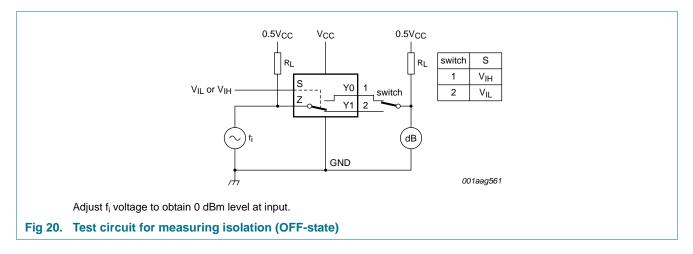
### 12.3 Test circuits

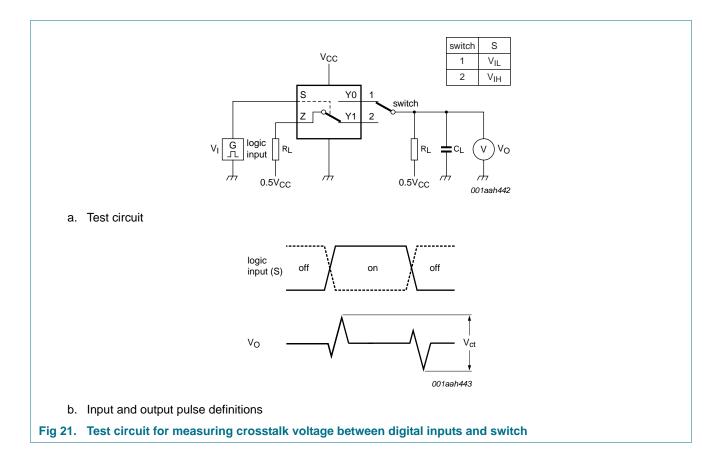


NX3L1G3157 Product data sheet

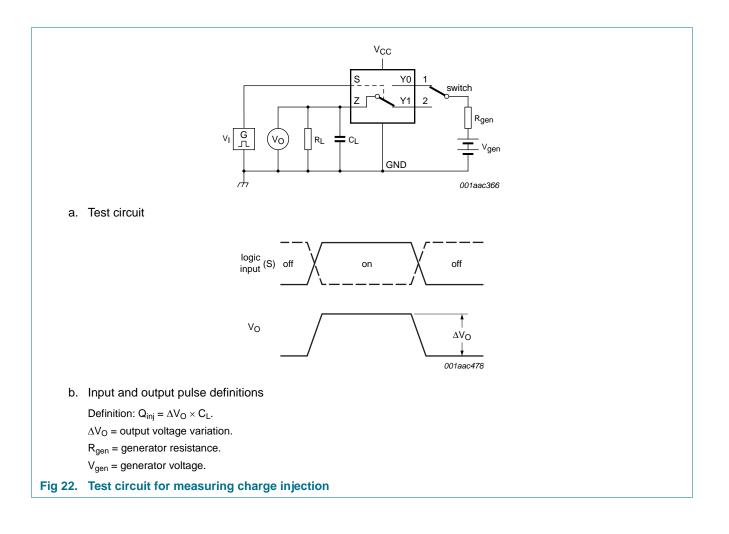
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# NX3L1G3157



# NX3L1G3157

Low-ohmic single-pole double-throw analog switch

### 13. Package outline

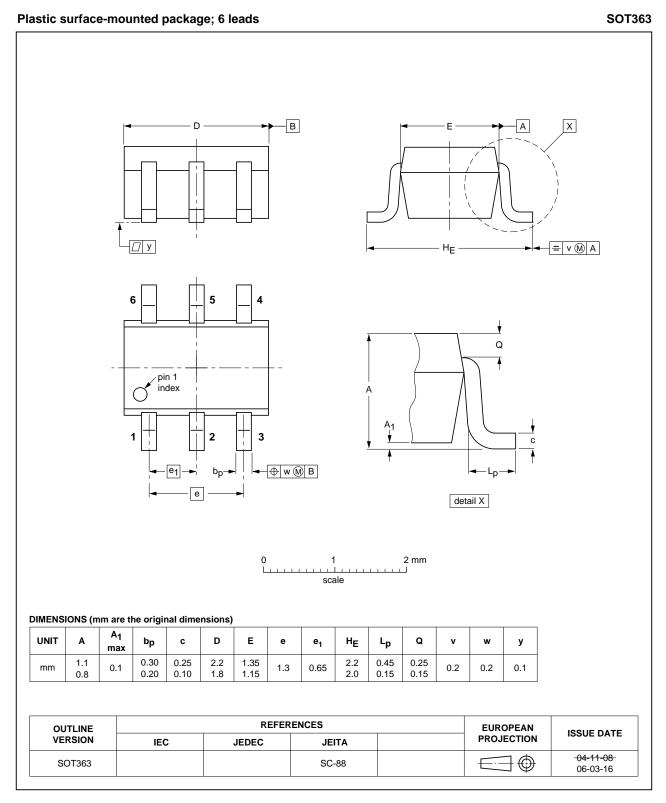
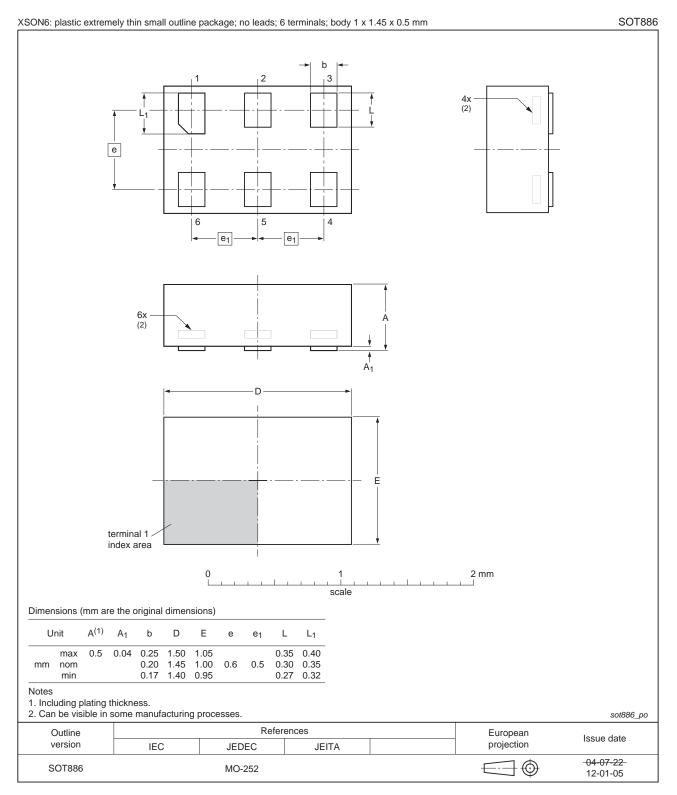


Fig 23. Package outline SOT363 (SC-88)

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NX3L1G3157

#### Low-ohmic single-pole double-throw analog switch



#### Fig 24. Package outline SOT886 (XSON6)

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NX3L1G3157

Low-ohmic single-pole double-throw analog switch

# 14. Abbreviations

AcronymDescriptionCDMCharged Device ModelCMOSComplementary Metal-Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelPDAPersonal Digital Assistant	Table 13.	e 13. Abbreviations		
CMOSComplementary Metal-Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	Acronym	Description		
ESD     ElectroStatic Discharge       HBM     Human Body Model       MM     Machine Model	CDM	Charged Device Model		
HBM     Human Body Model       MM     Machine Model	CMOS	Complementary Metal-Oxide Semiconductor		
MM Machine Model	ESD	ElectroStatic Discharge		
	HBM	Human Body Model		
PDA Personal Digital Assistant	MM	Machine Model		
	PDA	Personal Digital Assistant		
TTL Transistor-Transistor Logic	TTL	Transistor-Transistor Logic		

# **15. Revision history**

### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1G3157 v.10	20120807	Product data sheet	-	NX3L1G3157 v.9
Modifications:	<ul> <li>Package ou</li> </ul>	Itline drawing of SOT886 (F	Figure 24) modified.	
NX3L1G3157 v.9	20111109	Product data sheet	-	NX3L1G3157 v.8
Modifications:	<ul> <li>Legal pages</li> </ul>	s updated.		
NX3L1G3157 v.8	20100426	Product data sheet	-	NX3L1G3157 v.7
NX3L1G3157 v.7	20100324	Product data sheet	-	NX3L1G3157 v.6
NX3L1G3157 v.6	20100208	Product data sheet	-	NX3L1G3157 v.5
NX3L1G3157 v.5	20090407	Product data sheet	-	NX3L1G3157 v.4
NX3L1G3157 v.4	20080730	Product data sheet	-	NX3L1G3157 v.3
NX3L1G3157 v.3	20080721	Product data sheet	-	NX3L1G3157 v.2
NX3L1G3157 v.2	20080415	Product data sheet	-	NX3L1G3157 v.1
NX3L1G3157 v.1	20071008	Product data sheet	-	-

Low-ohmic single-pole double-throw analog switch

# **16. Legal information**

#### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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#### Low-ohmic single-pole double-throw analog switch

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Low-ohmic single-pole double-throw analog switch

### **18. Contents**

1	General description 1
2	Features and benefits 1
3	Applications 2
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information 3
7.1	Pinning
7.2	Pin description 3
8	Functional description 3
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Test circuits 6
11.2	ON resistance 7
11.3	ON resistance test circuit and graphs 8
12	Dynamic characteristics 10
12.1	Waveform and test circuits 11
12.2	Additional dynamic characteristics 13
12.3	Test circuits 13
13	Package outline 17
14	Abbreviations 19
15	Revision history 19
16	Legal information 20
16.1	Data sheet status 20
16.2	Definitions 20
16.3	Disclaimers
16.4	Trademarks 21
17	Contact information 21
18	Contents 22

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